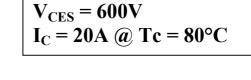
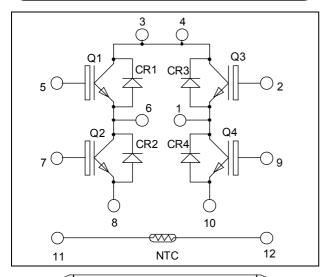
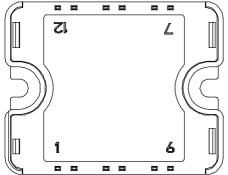


Full bridge Trench + Field Stop IGBT3 Power Module







Pins 3/4 must be shorted together

Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Trench + Field Stop IGBT3 Technology
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 20 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Very low stray inductance
 - Symmetrical design
- Internal thermistor for temperature monitoring
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS Compliant

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage		600	V
ī	Continuous Collector Current	$T_C = 25^{\circ}C$	32	
I_{C}	Continuous Conector Current T		20	A
I_{CM}	Pulsed Collector Current	$T_C = 25^{\circ}C$	40	
V_{GE}	Gate – Emitter Voltage		±20	V
P_{D}	Maximum Power Dissipation	$T_C = 25^{\circ}C$	62	W
RBSOA	Reverse Bias Safe Operating Area	$T_J = 150$ °C	40A @ 550V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 600V$				250	μΑ
V _{CE(sat)}	Collector Emitter Saturation Voltage	$V_{GE} = 15V$	$T_j = 25^{\circ}C$		1.5	1.9	V
		$I_{\rm C} = 20 {\rm A}$ $T_{\rm j} = 150 {\rm ^{\circ}C}$		1.7		V	
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 300 \mu A$		5.0	5.8	6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE}$	= 0V			300	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$ $V_{CE} = 25V$ $f = 1MHz$			1100		
Coes	Output Capacitance				70		pF
C_{res}	Reverse Transfer Capacitance				35		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (25°C)			110		
T_{r}	Rise Time	$V_{GE} = \pm 15V$			45		ns
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 300V$ $I_{\text{C}} = 20A$			200		
T_{f}	Fall Time	$R_G = 12\Omega$			40		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (150°C) $V_{GE} = \pm 15V$ $V_{Bus} = 300V$			120		ns
T _r	Rise Time				50		
$T_{d(off)}$	Turn-off Delay Time	$I_C = 20A$			250		
$T_{\rm f}$	Fall Time	$R_G = 12\Omega$			60		
Eon	Turn-on Switching Energy	$V_{GE} = \pm 15V$	$T_j = 25^{\circ}C$		0.11		mJ
Lon	Turn-on Switching Energy	$V_{\text{Bus}} = 300 \text{V}$	$T_{j} = 150^{\circ}C$		0.2		1113
E_{off}	Turn-off Switching Energy	D 100	$T_j = 25^{\circ}C$		0.5		mJ
Loff		$R_G = 12\Omega$ $T_j = 150$ °C			0.7		1113

Reverse diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			600			V
I_{RM}	Maximum Reverse Leakage Current	V _R =600V	$T_j = 25$ °C			100	пΔ
1 _{RM}	Waximum Reverse Leakage Current		$T_{j} = 150^{\circ}C$			350	μA
I_F	DC Forward Current		Tc = 80°C		20		Α
$V_{\rm F}$	Diode Forward Voltage	$I_F = 20A$ $V_{GE} = 0V$	$T_i = 25$ °C		1.6	2	
V F	Diode Forward Voltage		$T_{i} = 150^{\circ}C$		1.5		V
t_{rr}	Reverse Recovery Time	$I_F = 20A$ $V_R = 300V$ $di/dt = 1600A/\mu s$	$T_j = 25^{\circ}C$		100		ns
·rr	Reverse Recovery Time		$T_{\rm j} = 150^{\circ}{\rm C}$		150		113
0	Reverse Recovery Charge		$T_j = 25$ °C		1.1		C
Q_{rr}	Reverse Recovery Charge		$T_{i} = 150^{\circ}C$		2.3		μС
Б	В		$T_j = 25$ °C		0.23		mJ
E_{r}	Reverse Recovery Energy		$T_{j} = 150^{\circ}C$		0.50		111J



Thermal and package characteristics

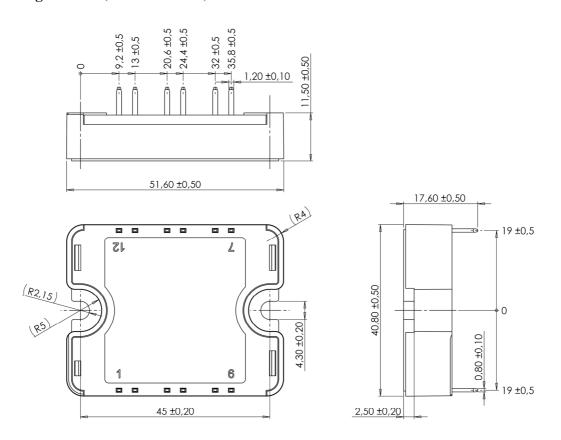
Symbol	Characteristic			Min	Тур	Max	Unit
R_{thJC}	lunction to Case Thermal Resistance	IGBT			2.4 。	°C/W	
		Diode			3.25		
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range		-40		175		
T_{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature	-40		100			
Torque	Mounting torque	To heatsink	M4	2	·	3	N.m
Wt	Package Weight	•	•			80	g

Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

Symbol	Characteristic	Min	Typ	Max	Unit
R ₂₅	Resistance @ 25°C		50		kΩ
B 25/85	$T_{25} = 298.15 \text{ K}$		3952		K

$$R_{T} = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature} \\ R_{T}: \text{ Thermistor value at T}$$

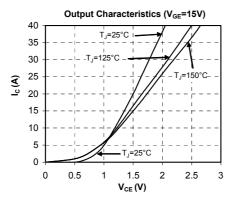
SP1 Package outline (dimensions in mm)

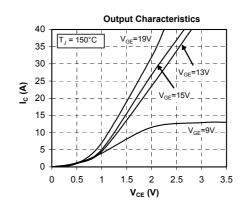


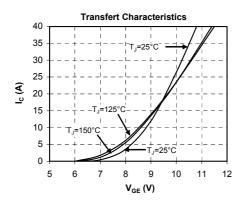
See application note 1904 - Mounting Instructions for SP1 Power Modules on www.microsemi.com

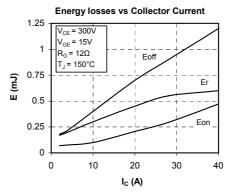


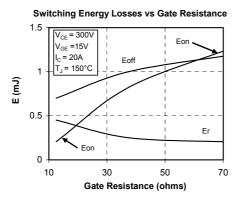
Typical Performance Curve

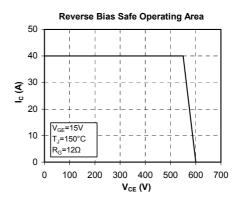


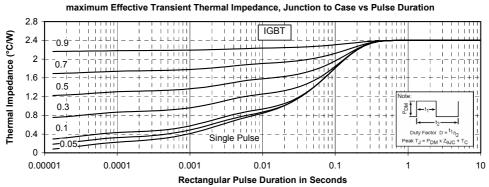




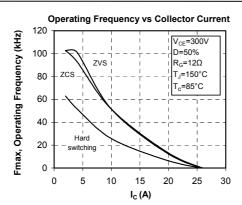


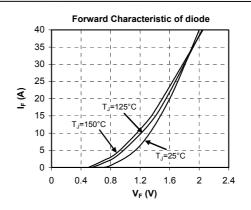


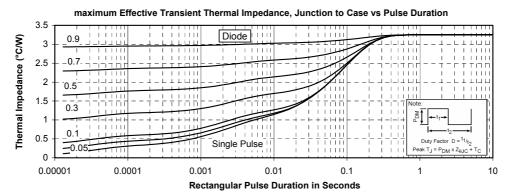














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